



# Photovoltaic cell back contact layer

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Effect of back contact electrode on the proposed inverted perovskite solar cell. Various metal back contact electrodes such as aluminium (4.26 eV), tin (4.42 eV) graphene (4.60 eV), silver (4.74 ...

1 INTRODUCTION TO PASSIVATING CONTACTS, OR JUNCTIONS. In state of the art, mass-produced silicon solar cells, thin layers of transparent dielectric materials like  $\text{SiO}_x$ ,  $\text{AlO}_x$ , and  $\text{SiN}_x$  are deposited on the front and back surfaces to reduce electron-hole recombination, except for a small portion, a mere 1-4%, where the metal electrodes make contact with n + and p + ...

Here we employ lasers to streamline back contact solar cell fabrication 46 and enhance power conversion efficiency. Our approach produces the first silicon 47 solar cell to exceed 27% efficiency ...

The management of charge carrier recombination and transport in heterojunction back contact solar cells poses significant challenges in achieving a high ...

The interdigitated back contact solar cell: a silicon solar cell for use in concentrated sunlight. IEEE Trans. Electron Devices 24, 337-341 (1977). Article Google Scholar

Transition metal oxide (TMO) is used as a selective injection medium for electron or hole injection. The alteration of the band alignment between the oxide layer and the CdTe, due to this alteration very low value of solar cell boundary contact at the back of the solar cell film [13]. TMO with a working function ranging from 3.5 to 7.0 eV.

The back contact is also commonly referred to as the hole transport material (HTM) in perovskites and is one factor limiting both ...

Thin-film photovoltaic (PV) devices based on the ternary chalcopyrite  $\text{Cu}(\text{In,Ga})\text{Se}_2$  (CIGS) 1,2,3 are among the most efficient thin-film solar cells 4, having demonstrated efficiencies of 20.8% 5 ...

The three energy-conversion layers below the antireflection layer are the top junction layer, the absorber layer, which constitutes the core of the device, and the back junction layer. Two additional electrical contact layers are needed to carry the electric current out to an external load and back into the cell, thus completing an electric ...

The best solar cell featuring top/rear contacts is an n-type solar cell featuring a boron-diffused emitter and a passivating rear contact. An efficiency of 25.8% [141], [142] has been demonstrated. Moreover, a world-record efficiency of 22.3% has been achieved by transferring this solar cell structure to n-type



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high-performance mc-Si [143].

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Although kesterite  $\text{Cu}_2\text{ZnSnS}_4$  (CZTS) has emerged as a potential absorber material for development of low cost thin film solar cells, the performance of the CZTS devices has been limited by a large deficit in open circuit voltage caused by recombinations of charge carriers primarily at the back contact interface. Recently, field passivation through engineering ...

To make a back-contact perovskite solar cell (BC-PSC), a quasi-interdigitated structure is used (Figure 1b), ... Meanwhile, an addnl. hot-pressed highly conductive low-temp. carbon layer on the back carbon electrode also reduces the RS. An enhanced PCE of 13.99% for 1 cm<sup>2</sup> PSCs by RS modulation is obtained, whereas the control device exhibits a ...

Here, the authors report a soln.-processed lead halide perovskite solar cell that has p-type NiO<sub>x</sub> and n-type ZnO nanoparticles as hole and electron transport layers, resp., and shows improved stability against H<sub>2</sub>O ...

Interdigitated back-contact (IBC) structure has been proposed and applied to crystalline silicon (c-Si) solar cells for a long time [1], [2], [3]. Due to the absence of front-side metal grid shielding, IBC solar cell has a high short-circuit current ( $J_{SC}$ ) and thus a high conversion efficiency ( $\eta$ ) [4], [5], [6]. Recently, the heterojunction back-contact (HBC) c-Si ...

The aluminium back surface field (Al-BSF) solar cell has been the working horse for the photovoltaic industry in the recent decades. However, from 2013 the industry is changing to the so-called PERC (passivated emitter rear contact) structure.

A hierarchical transparent back contact leveraging an AlGaO<sub>x</sub> passivating layer, Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub> MXene with a high work function, and a transparent cracked film lithography (CFL) templated nanogrid is demonstrated on copper-free cadmium telluride (CdTe) devices. AlGaO<sub>x</sub> improves device open-circuit voltage but reduces the fill factor when using a CFL-templated ...

In this work, TiB<sub>2</sub> thin films have been employed as intermediate layer between absorber and back contact in  $\text{Cu}_2\text{ZnSnS}_4$  (CZTS) thin film solar cells for interface optimization. It is found that the TiB<sub>2</sub> intermediate layer can significantly inhibit the formation of MoS<sub>2</sub> layer at absorber/back contact interface region, greatly reduces the series resistance ...

By an abrupt rise in the power conservation efficiency (PCE) of perovskite solar cells (PSCs) within a short span of time, the instability and toxicity of lead were raised as major hurdles in the path toward their commercialization. The usage of an inorganic lead-free CsSnI<sub>3</sub>-based halide perovskite offers the advantages



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of enhancing the stability and degradation ...

A thin-film solar cell is made by depositing one or more thin layers of PV material on a supporting material such as glass, plastic, or metal. ... and copper indium gallium diselenide (CIGS). Both materials can be deposited directly onto either the front or back of the module surface. CdTe is the second-most common PV material after silicon ...

Hybrid organic-inorganic lead halide photo-absorbers have revolutionized the field of photovoltaics, leading to an unparalleled rate of development of perovskite solar cells (PSCs), which have recently achieved a power conversion efficiency (PCE) of 25.7% [1]. Currently, high efficiency PSCs can have either a p-i-n or n-i-p structure, in which the perovskite layer ...

A conventional crystalline silicon solar cell (as of 2005). Electrical contacts made from busbars (the larger silver-colored strips) and fingers (the smaller ones) are printed on the silicon wafer. Symbol of a Photovoltaic cell. A solar cell or photovoltaic cell (PV cell) is an electronic device that converts the energy of light directly into electricity by means of the photovoltaic effect. [1]

Here,  $(E_g)^{\text{PV}}$  is equivalent to the SQ bandgap of the absorber in the solar cell;  $q$  is the elementary charge;  $T_A$  and  $T_S$  are the temperatures (in Kelvin) of the solar cell ...

A conventional crystalline silicon solar cell (as of 2005). Electrical contacts made from busbars (the larger silver-colored strips) and fingers (the smaller ones) are printed on the silicon wafer. Symbol of a Photovoltaic cell. A solar cell or ...

A material that is suitable as a back contact in a superstrate CdTe solar cell needs to fulfill a number of design criteria: (i) interfacial chemical stability with CdTe to prevent the formation of undesired secondary phases; (ii) ...

Aiming to simplify module manufacturing and reduce costs, it has been proposed to integrate bypass diodes directly in the structure of the solar cell. 24, 25 Although implementation of integrated bypass diodes in front-back contact (FBC) solar cells requires additional fabrication steps and may reduce the active area of the device, 26 ...

The tunnel oxide passivated contact (TOPCon) structure got more consideration for development of high performance solar cells by the introduction of a tunnel oxide layer between the substrate and ...

Here we increase the efficiency of back junction SHJ solar cells with improved back contacts consisting of p-type doped nanocrystalline silicon and a transparent conductive ...

Copper Indium Gallium Selenide (CIGS) is a thin-film solar cells that have emerged as a promising technology for cost-effective and efficient photovoltaic cells. To increase the efficiency of CIGS solar cells,



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integration of back contact with different materials was investigated utilizing Simulator SCAPS-1D and achieved an efficiency of 26.03%. The ...

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